TOSHIBA Field Effect Transistor Silicon N Channel Dual Gate MOS Type

3SK260

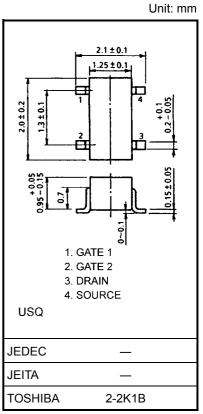
TV Tuner VHF Mixer Applications VHF RF Amplifier Applications

• High conversion gain: GCS = 24.5dB (typ.)

• Low noise figure: NFCS = 3.3dB (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	13.5	V
Gate 1-source voltage	V _{G1S}	±8	V
Gate 2-source voltage	V _{G2S}	±8	V
Drain current	I _D	30	mA
Drain power dissipation	P _D	100	mW
Channel temperature	T _{ch}	125	°C
Storage temperature range	T _{stg}	−55~125	°C

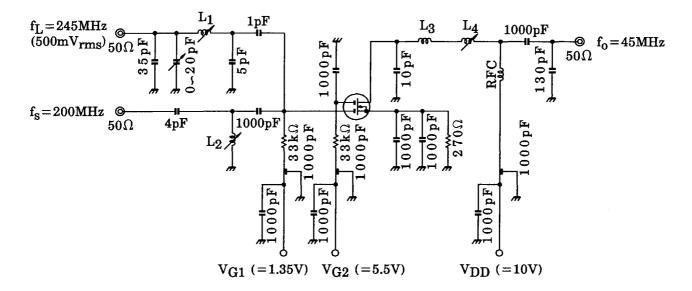


Weight: 0.006 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate 1 leakage current		I _{G1SS}	$V_{DS} = 0$, $V_{G1S} = \pm 6$ V, $V_{G2S} = 0$	_	_	±50	nA
Gate 2 leakage current		I _{G2SS}	$V_{DS} = 0, V_{G1S} = 0, V_{G2S} = \pm 6 \text{ V}$	_	_	±50	nA
Drain-source voltage		V (BR) DSX	$V_{G1S} = -4 \text{ V}, V_{G2S} = -4 \text{ V}$ $I_D = 100 \mu\text{A}$	15	_	_	V
Drain current	(Note)	I _{DSS}	$V_{DS} = 6 \text{ V}, V_{G1S} = 0, V_{G2S} = 3 \text{ V}$	3	_	14	mA
Gate 1-source cut-off voltage		V _{G1S} (OFF)	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V}, I_D = 100 \mu\text{A}$	-0.15	_	-1.5	V
Gate 2-source cut-off voltage		V _{G2S} (OFF)	$V_{DS} = 6 \text{ V}, V_{G1S} = 0 \text{ V}, I_D = 100 \mu\text{A}$	0	_	-1.0	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V}, I_D = 10 \text{ mA}$ f = 1 kHz	_	27	—	mS
Input capacitance		C _{iss}	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V}, I_D = 10 \text{ mA}$	_	2.7	3.8	pF
Reverse transfer capacitance		C _{rss}	f = 1 MHz	_	0.025	0.04	pF
Conversion gain		G _{CS}	V _{DD} = 10 V, f = 200 MHz	21	24.5	_	dB
Noise figure		NF _{CS}	f _L = 245 MHz (500 mV _{rms}) (Figure 1)		3.3	5.5	dB

Note: I_{DSS} classification Y: 3~7 mA, GR: 6~14 mA



L₁: ϕ 6.5 mm bobbin with ferrite core, ϕ 0.7 mm UEW, 2 T

L₂: ϕ 6.5 mm bobbin with ferrite core, ϕ 0.7 mm UEW, 2 T

L₃: 3 mm ID, ϕ 0.5 mm UEW, 4 T

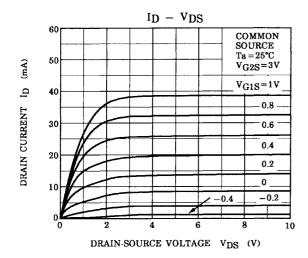
L₄: ϕ 8 mm bobbin with ferrite core, ϕ 0.35 mm UEW, 7 T

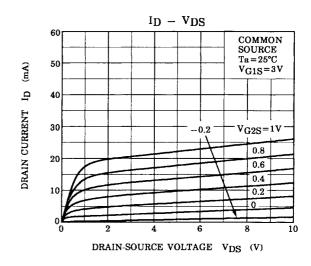
RFC: 100 μH

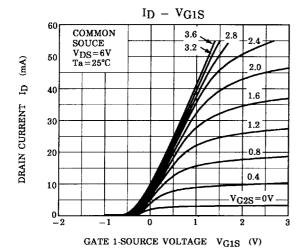
Figure 1 G_{CS} and NF_{CS} Test Circuit

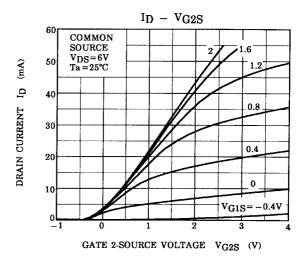
Marking

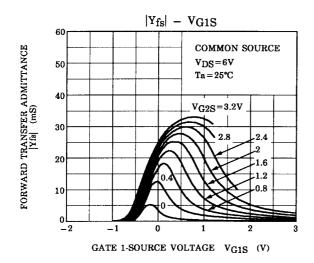


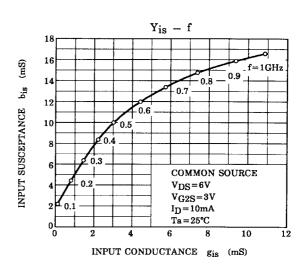


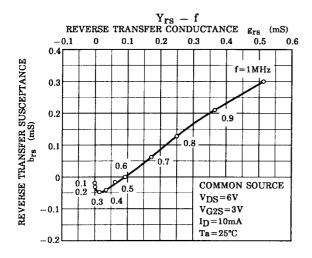


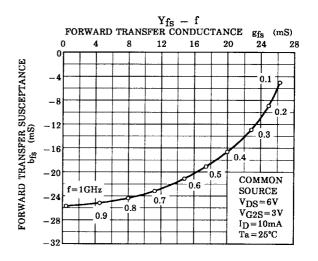


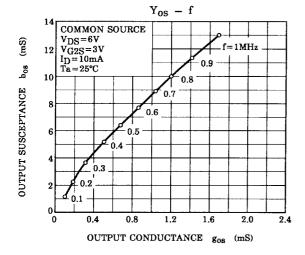


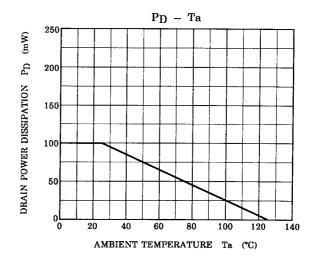


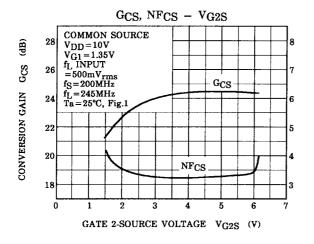


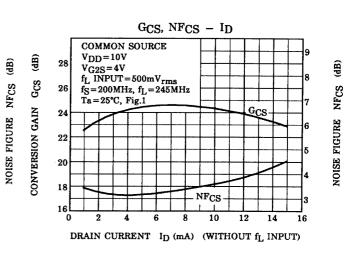


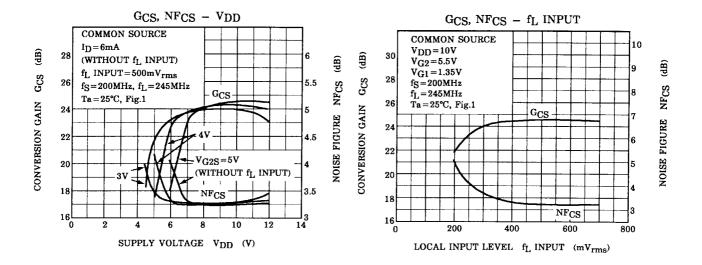












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